

# PRODUCT/PROCESS CHANGE NOTIFICATION

PCN APM-IPC/09/4684 Notification Date 06/23/2009

IPC PRODUCTS IN SO8/14/16 LEAD NRS & STAND-ALONE
ASSEMBLY LINE using Halogen-free materials in ST Bouskoura (Morocco)

#### **Table 1. Change Implementation Schedule**

Forecasted implementation date for change	30-Jun-2009
Forecasted availabillity date of samples for customer	30-Jun-2009
Forecasted date for <b>STMicroelectronics</b> change Qualification Plan results availability	16-Jun-2009
Estimated date of changed product first shipment	19-Sep-2009

#### **Table 2. Change Identification**

Related APCN	4217
Product Identification (Product Family/Commercial Product)	as per attached list
Type of change	Package assembly material change
Reason for change	resin compound change for HF
Description of the change	In order to implement the request of the Restricted Flame Retardant products, the assembly of the halogen-free products in SO-8 lead package will be made in Bouskoura. This change will apply to the standard products made in Bouskoura as well as to the halogen-free products which are currently produced at subcontractor Amkor. The involved products can be assembled in both SOSA and NRS to achieve the maximum production flexibility.
Product Line(s) and/or Part Number(s)	See attached
Description of the Qualification Plan	See attached
Change Product Identification	by finished good code
Manufacturing Location(s)	

**47**/.

Table	3 I	ist (	of .	Attac	hments

Customer Part numbers list	
Qualification Plan results	

PCN APM-IPC/09/4684
Notification Date 06/23/2009
Name:
Title:
Company:
Date:
Signature:

**47/**.

#### **DOCUMENT APPROVAL**

Name	Function
Gattavari, Giuseppe	Division Marketing Manager
Pulicelli, Fulvio	Division Product Manager
Motta, Antonino	Division Q.A. Manager

**A7**/.



#### ATTACHMENT TO PCN APM-IPC/09/4684

## IPC PRODUCTS in SO8/14/16 lead NRS & STAND-ALONE ASSEMBLY LINE using Halogen-free materials in ST Bouskoura (Morocco)

#### WHAT:

IPC Division, in close cooperation with the Central/Corporate functions, decided to concentrate all the SO8/14/16 lead assembly activities in Bouskoura plant, in order to optimize the production performances and have the right flexibility in deliveries.

Furthermore IPC decided to convert all its SO8/14/16 lead production, complying with the latest environmental requests of the Restricted Flame Retardant resin (halogen-free).

The p/n involved are the following:

Decales at 1 in a	(
Product Line	<b>p/n</b>
L09603	UC2842BD1
L09603	UC2842BD1013TR
L09603	UC3842BD1
L09603	UC3842BD1013TR
L12703	UC2845BD1
L12703	UC2845BD1013TR
L12703	UC3845BD1
L12703	UC3845BD1013TR
L26403	UC2843BD1
L26403	UC2843BD1013TR
L26403	UC3843BD1
L26403	UC3843BD1013TR
L28903	UC2844BD1
L28903	UC2844BD1013TR
L28903	UC3844BD1
L28903	UC3844BD1013TR
U07301	FLEX01D
U07301	FLEX01DTR
U09303	FL28289013TR
U09303	L6561D
U09303	L6561D013TR
U09403	L6565D
U09403	L6565DTR
UE2703	L6562D
UE2703	L6562DTR
UE3801	IPC10
UE3801	IPC10TR
UE3801	L6562AD
UE3801	L6562ADTR
UE3801	L6562ATD
UE3801	L6562ATDTR



### ATTACHMENT TO PCN APM-IPC/09/4684

Product line p/n

030301 TSM103WAID 030301 TSM103WAIDT 030301 TSM103WID 030301 TSM103WIDT

#### WHY:

- 1. Concentrate SO package in Bouskoura plant
- 2. Comply with the latest market requirements in terms of Halogen-free products

#### **HOW**

According to the attached reliability report.

The involved products can be assembled in both SOSA and NRS to achieve the maximum production flexibility.

#### WHEN:

The mass production could start by September 2009 and the relevant samples are available upon request.

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Q&R Project Code: RR000709CT6017

Q&R Project date:19-05-2009

## **QUALITY & RELIABILITY EVALUATION REPORT**

## QUALIFICATION OF SOIC 8/14/16L NRS & STAND ALONE LINE

#### **USING HF (HALOGEN FREE) MATERIALS**

SUMITOMO G700K MOLDING COMPOUND AND NEW GLUE ABLEBOND 8601S25

## ST-BOUSKOURA(MOROCCO) B-END

#### **Abstract:**

APM/I&PC Division , decide to concentrate all the SOIC8/14/16L assembly activities in BSK plant, in order to optimize the production performance and have the right flexibility in delivery in compliance to the new ROHS procedure about the Halogen Free standard.

#### See HF IPC-JEDEC spec. as reference:

JAPAN:JPCA-ES-01 IEC STANDARD:61249-2-21 JEDEC J-101

#### **Conclusion:**

A full qualification exercise it was done with, Workability/Testing/C.A/Reliability evaluation positive results, to qualify the new Halogen Free products assembled on SOIC8/14/16L NRS/STAND ALONE line using SUMITOMO G700K, and ABLEBOND 8601S25 as new glue type.( Both already qualified in different I&PC family products see RR:000609CT6017- date 15-05-2009) having as test vehicles:

\*U093 (BCD1 family)

\*L264/0303 (BIP family)

\*UM06/07 (BCD6s family)

Note:

Product pass JEDEC LEVEL \_1\_3@260°C

Product is classified as ECOPAK E4

Issued by

Francesco Ventura (I&PC QA&R B-END)

Approved by

Antonino Motta (I&PC /QA&R MNG )

## Preliminary Reliability test conditions and results for \*U093

Test	Test short description  Performed on 3# STD assy lots									
	Method	Conditions	Sample /Lots	Number of lots 1	Duration	Results Fail/SS				
PC	Pre-Condition	ing: Moisture sensitivit	y level@1							
	SAM T=0 & AFTER PRECOND	DUT SMD Preconditioning JL1 Bake 24hrs @ 125°C Soak 168hrs @ 85°C / 85%RH 3X Reflow @ 260°C	154			0/154 NO- DELAMINATION Before and after precond.				
<b>E.S</b> :	Preconditioning JL@1 + Pressure pot									
	Condtions:	2atm	77		168hrs	0/77				
<b>E.S</b> :	Preconditioning	JL@1 + Thermal Cycle								
	Conditions:Ta=	=-65°C/+150°C	77		1000Cy	0/77				
HTS	High Temperatu	ıre Storage								
	No bias	Tamb=150°C	77		1000h	0/77				

DIE FEATURES			PACKAGE FEATURES			
Die Code	:	XU093ADZ	Technical code(PKG)	:	O7	
Diffusion process	:	A3 BCD1	Package name	:	SOIC 8LN	
Wafer diameter	:	6"	Assembly site	:	BSK(MOROCCO)	
Diffusion site	:	AMOKIO	Leadframe / substrate	:	SO8L 94x125 MILS MTX PPF	
Die size	:	2590 X2060UM	Die attach	:	GLUE ABLESTIK 8601S25	
Die Tick.	:	$375 \pm 25 \ \mu m$	Molding compound	:	SUMITOMO G700K GREEN COMPOUND (HF)	
Passivation	:	SiN	Wire Bonding	:	1.0 mils Au	
Back finishing	:	CHROMO NICKEL GOLD	Solder balls / plating	:	Ni/Pd/Au	

## Preliminary Reliability test conditions and results for \*L264

Test	Test short description  Performed on 3# STD assy lots									
	Method	Conditions	Sample	Number of	Duration	Results				
			/Lots	lots 1		Fail/SS				
PC	Pre-Condition	ing: Moisture sensitivit	y level@1							
	SAM T=0 & AFTER PRECOND	DUT SMD Preconditioning JL1 Bake 24hrs @ 125°C Soak 168hrs @ 85°C / 85%RH 3X Reflow @ 260°C	77			0/77 NO- DELAMINATION Before and after precond.				
<b>E.S</b> :	Preconditioning JL@1 + Pressure pot									
	Condtions:	2atm	77		168hrs	0/77				
<b>E.S</b> :	Preconditioning JL@1 + Thermal Cycle									
	Conditions:Ta=	=-65°C/+150°C	77		100Cy	0/77				
HTS	High Temperature Storage									
	No bias	Tamb=150°C	77		100h	0/77				

DIE FEATURES			PACKAGE FEATURES		
Die Code	:	XL264EA6	Technical code(PKG)	:	O7
Diffusion process	:	C1 BIP	Package name	:	SOIC 8LN
Wafer diameter	:	6"	Assembly site	:	BSK(MOROCCO)
Diffusion site	:	AMOKIO	Leadframe / substrate	:	SO8L 94x125 MILS MTX PPF
Die size	:	2440 X1940UM	Die attach	:	GLUE ABLESTIK 8601S25
Die Tick.	:	$280 \pm 20 \; \mu m$	Molding compound	:	SUMITOMO G700K GREEN COMPOUND (HF)
Passivation	:	SiN	Wire Bonding	:	1.0 mils Au
Back finishing	:	CHROMO NICKEL	Solder balls / plating	:	Ni/Pd/Au

## Preliminary Reliability test conditions and results for \*0303

Test	Test short desc	ription									
	Performed on 3# STD assy lots										
	Method	Conditions	Sample /Lots	Number of lots 1	Duration	Results Fail/SS					
PC	Pre-Conditioning: Moisture sensitivity level@1										
	SAM T=0 & AFTER PRECOND	DUT SMD Preconditioning JL3 Bake 24hrs @ 125°C Soak 192hrs @ 30°C / 60%RH 3X Reflow @ 260°C	77			0/77 NO- DELAMINATION Before and after precond.					
<b>E.S</b> :	Preconditioning JL@1 + Pressure pot										
	Condtions:	2atm	77		168hrs	0/77					
<b>E.S</b> :	Preconditioning JL@1 + Thermal Cycle										
	Conditions:Ta=	-65°C/+150°C	77		1000Cy	0/77					
HTS	High Temperatu	re Storage									
	No bias	Tamb=150°C	77		1000h	0/77					
ТНВ	Temperature Humidty Bias	(A2) 85°C/85%RH, Vin=32V	45		1000h	0/45					

DI	DIE FEATURES PACKAGE FEATURES				
Die Code	:	X0303AC6	Technical code(PKG)	:	O7
Diffusion process	:	C6 BIP	Package name	:	SOIC 8LN
Wafer diameter	:	6"	Assembly site	:	BSK(MOROCCO)
Diffusion site	:	AMOKIO	Leadframe / substrate	:	SO8L 94x125 MILS MTX PPF
Die size	:	18900 X 2120UM	Die attach	:	GLUE ABLESTIK 8601S25
Die Tick.	:	$375 \pm 25 \mu m$	Molding compound	:	SUMITOMO G700K GREEN COMPOUND (HF)
Passivation	:	SiN-POLYAMMIDE	Wire Bonding	:	1.0 mils Au
Back finishing	:	ROW SILICON	Solder balls / plating	:	Ni/Pd/Au

## Preliminary Reliability test conditions and results for \*UM06

Test	Test short description									
	Performed on 3# STD assy lots									
	Method	Conditions	Sample	Number of	Duration	Results				
			/Lots	lots 1		Fail/SS				
PC	Pre-Conditioning: Moisture sensitivity level@1									
	SAM T=0 & AFTER PRECOND	DUT SMD Preconditioning JL1 Bake 24hrs @ 125°C Soak 168hrs @ 85°C / 85%RH 3X Reflow @ 260°C	77			0/77 NO- DELAMINATION Before and after precond.				
<b>E.S</b> :	Preconditionin	ng JL@1 + Pressure pot	ţ							
	Condtions:	2atm	77		168hrs	0/77				
<b>E.S</b> :	Preconditioning	JL@1 + Thermal Cycle								
	Conditions:Ta=	=-65°C/+150°C	77		1000Cy	0/77				
HTS	High Temperature Storage									
	No bias	Tamb=150°C	77		1000h	0/77				

DIE FEATURES		PACKAGE FEATURES			
Die Code	:	XUM06AEP	Technical code(PKG)	:	O7
Diffusion process	:	2L BCD6s	Package name	:	SOIC 8LN
Wafer diameter	:	6"	Assembly site	:	BSK(MOROCCO)
Diffusion site	:	AMOKIO	Leadframe / substrate	:	SO8L 85x85 MILS MTX PPF
Die size	:	1311 X 1242UM	Die attach	:	GLUE ABLESTIK 8601S25
Die Tick.	:	$375 \pm 25 \ \mu m$	Molding compound	:	SUMITOMO G700K GREEN COMPOUND (HF)
Passivation	:	USG-SiON-PIX	Wire Bonding	:	1.0 mils Au
Back finishing	:	CHROMO NICKEL GOLD	Solder balls / plating	:	Ni/Pd/Au

## **ATTACHMENT 1: RELIABILITY TEST DESCRIPTION**(for reference)

TEST NAME	DESCRIPTION	PURPOSE
JLn: Jedec Level n surface mounting simulation	The device is submitted to a typical temperature profile used for surface mounting, after a controlled moisture absorption.	As stand-alone test: to investigate the level of moisture sensitivity.  As preconditioning before other reliability tests: to verify that the surface mounting stress does not impact on the subsequent reliability performance.  The typical failure modes are "pop corn" effect and delamination.
TCT: Temperature Cycles Test	The device is submitted to cycled temperature excursions, between a hot and a cold chamber in air atmosphere.	To investigate failure modes related to the thermomechanical stress induced by the different thermal expansion of the materials interacting in the diepackage system. Typical failure modes are linked to metal displacement, dielectric cracking, moulding compound delamination, wire-bonds failure, die-attach layer degradation.
PPT: Pressure Pot Test	The device is stored in saturated steam, at fixed and controlled conditions of pressure and temperature.	To investigate corrosion phenomena affecting die or package materials, related to chemical contamination and package hermeticity.
HTS: High Temperature Storage	The device is stored in unbiased condition at the max. temperature allowed by the package materials, sometimes higher than the max. operative temperature.	To investigate the failure mechanisms activated by high temperature, typically wire-bonds solder joint ageing, data retention faults, metal stress-voiding.
<b>THB:</b> Temperature Humidity Bias Test	The device is biased in static configuration minimizing its internal power dissipation, and stored at controlled conditions of ambient temperature and relative humidity.	To investigate failure mechanisms activated in the die-package environment by electrical field and wet conditions. Typical failure mechanisms are electrochemical corrosion and surface effects related to the moulding compound.



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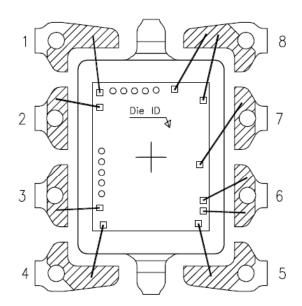
DOCUMENT 7862867 REVISION A CONTROLLED DOCUMENT (Check latest revision) DATE 09-JUN-2005 page: 1/1

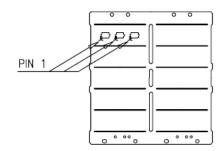
BONDING DIAGRAM FOR LINE: PACKAGE: 07 U093

FRAME PAD : .094 x .125 2,388 x 3,175 inch

mm



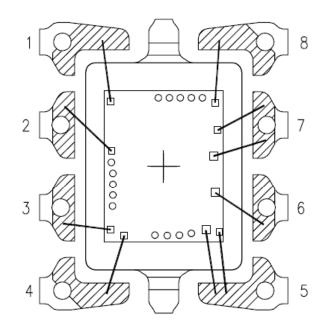


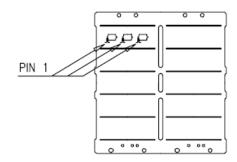


BONDING DIAGRAM FOR LINE : L 7 64

FRAME PAD : .094 x .125 inch 2,388 x 3,175 mm PACKAGE: 07

SCALE L\_\_\_\_\_l 1mm



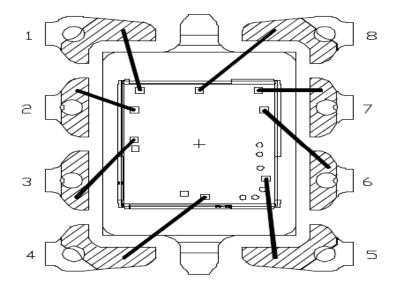


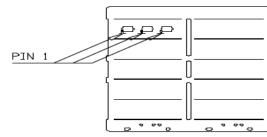
# & APM – Analog, Power & MEMS Group - Q&R Back End Process Quality Assurance

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BONDING DIAGRAM FOR LINE: 0303

PACKAGE: 0 7

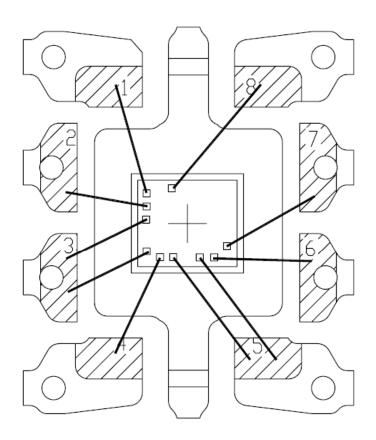




SOP 8L MATRIX BLANK BOND. DIAG. REF. : 0108482

## MOUNT & BOND DIAGRAM FOR B507\*UM06AEP

FRAME PAD :  $\frac{85 \times 85 \text{ mils}}{2,159 \times 2,159 \text{ mm}}$ 



SCALE : 1 mm

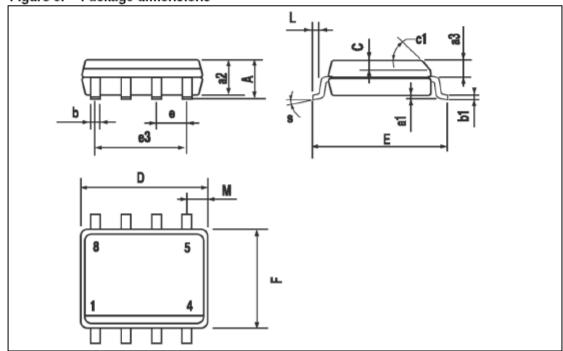


E.S.D. PROGRAM IS MANDATORY

Table 9. SO-8 mechanical data

Dim		mm		inch					
Dim.	Min	Тур	Max	Min	Тур	Max			
Α			1.75			0.068			
a1	0.1		0.25	0.003		0.009			
a2			1.65			0.064			
a3	0.65		0.85	0.025		0.033			
b	0.35		0.48	0.013		0.018			
b1	0.19		0.25	0.007		0.010			
С	0.25		0.5	0.010		0.019			
c1		•	45 (	(typ.)	•	•			
D	4.8		5.0	0.188		0.196			
E	5.8		6.2	0.228		0.244			
е		1.27			0.050				
e3		3.81			0.150				
F	3.8		4.0	0.14		0.157			
L	0.4		1.27	0.015		0.050			
М			0.6			0.023			
s		8º (max.)							

Figure 9. Package dimensions



Nome file: SO8NRS\_HF.doc

Directory: C:\Documents and Settings\francesco ventura\My Documents Modello: C:\Documents and Settings\francesco ventura\Application

Oggetto:

Autore: st

Parole chiave: Commenti:

Data creazione: 5/14/2009 5:09:00 PM

Numero revisione: 34

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Tempo totale modifica 223 minuti

Data ultima stampa: 6/3/2009 5:09:00 PM

Come da ultima stampa completa Numero pagine: 11

Numero pagine: 11 Numero parole: 1,342 (circa)

Numero caratteri: 1,342 (circa)
7,654 (circa)

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